

## Features

- Industry Standard Architecture
  - Low-cost Easy-to-use Software Tools
- High-speed, Electrically Erasable Programmable Logic Devices
- CMOS and TTL Compatible Inputs and Outputs
  - Input and I/O Pull-up Resistors
- Advanced Flash Technology
  - Reprogrammable
  - 100% Tested
- High-reliability CMOS Process
  - 20 year Data Retention
  - 100 Erase/Write Cycles
  - 2,000V ESD Protection
  - 200mA Latchup Immunity
- Full Military Temperature Ranges
- Dual-in-line and Surface Mount Packages in Standard Pinouts
- PCI Compliant

Figure 0-1. Logic Diagram



Figure 0-2. Pin Configurations

All Pinouts Top View

Pin Name	Function
CLK	Clock
IN	Logic Inputs
I/O	Bidirectional Buffers
*	No Internal Connection
V <sub>CC</sub>	+5V Supply



High-performance  
Electrically  
Erasable  
Programmable  
Logic Device

Atmel ATF22V10B



## 1. Description

The Atmel® ATF22V10B is a high-performance CMOS (electrically erasable) programmable logic device (PLD) which utilizes the Atmel proven electrically erasable Flash memory technology. Speeds down to 7.5ns and power dissipation as low as 10mA are offered. All speed ranges are specified over the full  $5V \pm 10\%$  range for military and industrial temperature ranges, and  $5V \pm 5\%$  for commercial temperature ranges.

Several low-power options allow selection of the best solution for various types of power-limited applications. Each of these options significantly reduces total system power and enhances system reliability.

## 2. Absolute Maximum Ratings\*

Temperature Under Bias .....	-55°C to +125°C
Storage Temperature .....	-65°C to +150°C
Voltage on Any Pin with Respect to Ground .....	-2.0V to +7.0V <sup>(1)</sup>
Voltage on Input Pins with Respect to Ground During Programming .....	-2.0V to +14.0V <sup>(1)</sup>
Programming Voltage with Respect to Ground .....	-2.0V to +14.0V <sup>(1)</sup>

\*NOTICE: Stresses beyond those listed under “Absolute Maximum Ratings” may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Note: 1. Minimum voltage is -0.6V DC, which may undershoot to -2.0V for pulses of less than 20ns. Maximum output pin voltage is  $V_{CC} + 0.75V$  DC, which may overshoot to 7.0V for pulses of less than 20ns.

## 3. DC and AC Operating Conditions

	Commercial	Industrial	Military
Operating Temperature	0°C - 70°C (Ambient)	-40°C - 85°C (Ambient)	-55°C - 125°C (Case)
$V_{CC}$ Power Supply	$5V \pm 5\%$	$5V \pm 10\%$	$5V \pm 10\%$

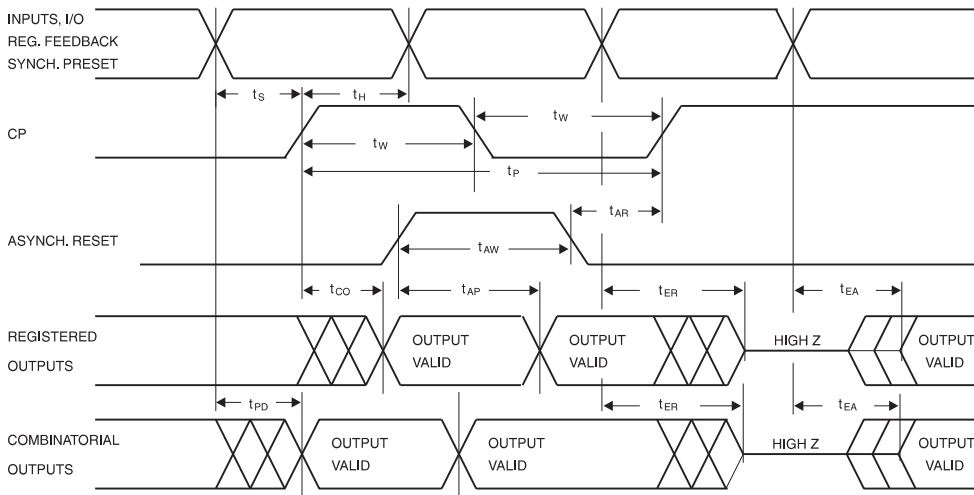
Note: 1. The shaded devices are obsolete

## 3.1 DC Characteristics

Symbol	Parameter	Condition	Min	Typ	Max	Units	
$I_{IL}$	Input or I/O Low Leakage Current	$0 \leq V_{IN} \leq V_{IL} \text{ (Max)}$		-35	-100	$\mu\text{A}$	
$I_{IH}$	Input or I/O High Leakage Current	$3.5 \leq V_{IN} \leq V_{CC}$			10	$\mu\text{A}$	
$I_{CC}$	Power Supply Current, Standby	$V_{CC} = \text{Max}, V_{IN} = \text{Max}, \text{Outputs Open}$	B-7	Com.	85	120	mA
				Ind., Mil.	85	140	mA
$I_{CC}$	Power Supply Current, Standby	$V_{CC} = \text{Max}, V_{IN} = \text{Max}, \text{Outputs Open}$	B-10	Com./Ind.	85/85	120/140	mA
				Mil.	85	140	mA
			B-15	Com./Ind.	65/65	90/115	mA
				Mil.	65	115	mA
			B-25	Com.	65	90	mA
				Ind., Mil.	65	115	mA
			BQ-15	Com.	35	55	mA
			BQL-20, -25	Com.	5	10	mA
Ind., Mil.	5	15		mA			
$I_{CC2}$	Clocked Power Supply Current	$V_{CC} = \text{Max}, \text{Outputs Open}, f = 15\text{MHz}$	B-7	Com.	90	120	mA
				Mil., Ind.	90	145	mA
			B-10	Com./Ind.	90/90	120/145	mA
				Mil.	90	150	mA
			B-15	Com./Ind.	65/65	90/120	mA
				Mil.	65	150	mA
			B-25	Com.	65	90	mA
				Ind., Mil.	65	120	mA
			BQ-15	Com.	40	60	mA
			BQL-20, -25	Com.	20	50	mA
Ind., Mil.	20	70		mA			
$I_{OS}^{(1)}$	Output Short Circuit Current	$V_{OUT} = 0.5\text{V}$			-130	mA	
$V_{IL}$	Input Low Voltage		-0.5		0.8	V	
$V_{IH}$	Input High Voltage		2.0		$V_{CC} + 0.75$	V	
$V_{OL}$	Output Low Voltage	$V_{IN} = V_{IH} \text{ or } V_{IL}, V_{CC} = \text{Min}$	$I_{OL} = 16\text{mA}$	Com., Ind.		0.5	V
			$I_{OL} = 12\text{mA}$	Mil.		0.5	V
$V_{OH}$	Output High Voltage	$V_{IN} = V_{IH} \text{ or } V_{IL}, V_{CC} = \text{Min}$	$I_{OH} = -4.0\text{mA}$	2.4		V	

- Notes: 1. Not more than one output at a time should be shorted. Duration of short circuit test should not exceed 30 sec  
 2. The shaded devices are obsolete

## 4. AC Waveforms<sup>(1)</sup>



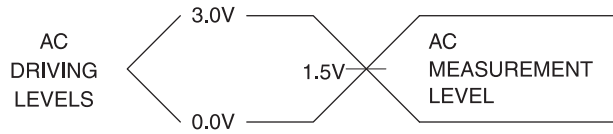
Note: 1. Timing measurement reference is 1.5V. Input AC driving levels are 0.0V and 3.0V, unless otherwise specified

## 5. AC Characteristics<sup>(1)</sup>

Symbol	Parameter	-10		-15		Units
		Min	Max	Min	Max	
$t_{PD}$	Input or Feedback to Combinatorial Output	3	10	3	15	ns
$t_{CO}$	Clock to Output	2	6.5	2	8	ns
$t_{CF}$	Clock to Feedback		2.5		2.5	ns
$t_S$	Input or Feedback Setup Time	4.5		10		ns
$t_H$	Hold Time	0		0		ns
$f_{MAX}$	External Feedback $1/(t_S + t_{CO})$	90		55.5		MHz
	Internal Feedback $1/(t_S + t_{CF})$	142		69		MHz
	No Feedback $1/(t_{WH} + t_{WL})$	142		83.3		MHz
$t_W$	Clock Width ( $t_{WL}$ and $t_{WH}$ )	3.5		6		ns
$t_{EA}$	Input or I/O to Output Enable	3	10	3	15	ns
$t_{ER}$	Input or I/O to Output Disable	3	9	3	15	ns
$t_{AP}$	Input or I/O to Asynchronous Reset of Register	3	12	3	20	ns
$t_{AW}$	Asynchronous Reset Width	8		15		ns
$t_{AR}$	Asynchronous Reset Recovery Time	6		10		ns
$t_{SP}$	Setup Time, Synchronous Preset	6		10		ns
$t_{SPR}$	Synchronous Preset to Clock Recovery Time	8		10		ns

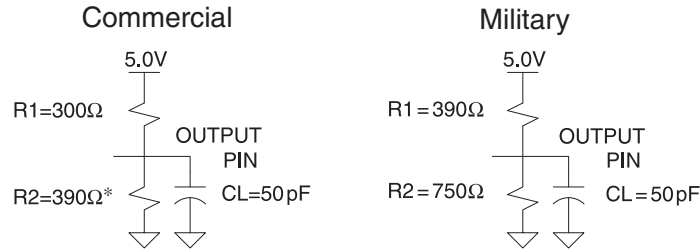
Notes: 1. See ordering information for valid part numbers

## 6. Input Test Waveforms and Measurement Levels



$t_R, t_F < 3ns$

## 7. Output Test Loads



\* All except -7 which is R2 = 300Ω

## 8. Pin Capacitance

$f = 1MHz, T = 25^{\circ}C^{(1)}$

	Typ	Max	Units	Conditions
$C_{IN}$	5	8	pF	$V_{IN} = 0V$
$C_{OUT}$	6	8	pF	$V_{OUT} = 0V$

Note: 1. Typical values for nominal supply voltage. This parameter is only sampled and is not 100% tested

## 9. Power-up Reset

The registers in the Atmel® ATF22V10B are designed to reset during power-up. At a point delayed slightly from  $V_{CC}$  crossing  $V_{RST}$ , all registers will be reset to the low state. The output state will depend on the polarity of the output buffer.

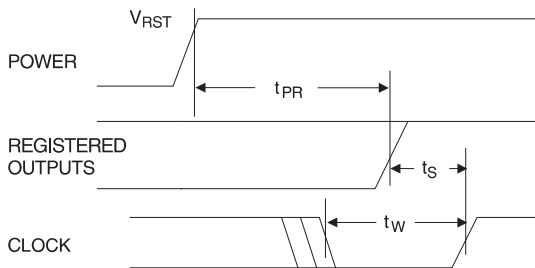
This feature is critical for state machine initialization. However, due to the asynchronous nature of reset and the uncertainty of how  $V_{CC}$  actually rises in the system, the following conditions are required:

1. The  $V_{CC}$  rise must be monotonic
2. After reset occurs, all input and feedback setup times must be met before driving the clock pin high
3. The clock must remain stable during  $t_{PR}$

## 10. Preload of Registered Outputs

The Atmel® ATF22V10B registers are provided with circuitry to allow loading of each register with either a high or a low. This feature will simplify testing since any state can be forced into the registers to control test sequencing. A JEDEC file with preload is generated when a source file with vectors is compiled. Once downloaded, the JEDEC file preload sequence will be done automatically by most of the approved programmers after the programming.

**Figure 10-1.**



**Table 10-1.**

Parameter	Description	Typ	Max	Units
$t_{PR}$	Power-up Reset Time	600	1,000	ns
$V_{RST}$	Power-up Reset Voltage	3.8	4.5	V

## 11. Security Fuse Usage

A single fuse is provided to prevent unauthorized copying of the ATF22V10B fuse patterns. Once programmed, fuse verify and preload are inhibited. However, the 64-bit User Signature remains accessible.

The security fuse should be programmed last, as its effect is immediate.

## 12. Electronic Signature Word

There are 64-bits of programmable memory that are always available to the user, even if the device is secured. These bits can be used for user-specific data.

## 13. Programming/Erasing

Programming/erasing is performed using standard PLD programmers. See *CMOS PLD Programming Hardware and Software Support* for information on software/programming.

## 14. Input and I/O Pull-ups

All Atmel® ATF22V10B family members have internal input and I/O pull-up resistors. Therefore, whenever inputs or I/Os are not being driven externally, they will float to  $V_{CC}$ . This ensures that all logic array inputs are at known states. These are relatively weak active pull-ups that can easily be overdriven by TTL-compatible drivers (see input and I/O diagrams below).

Figure 14-1. Input Diagram

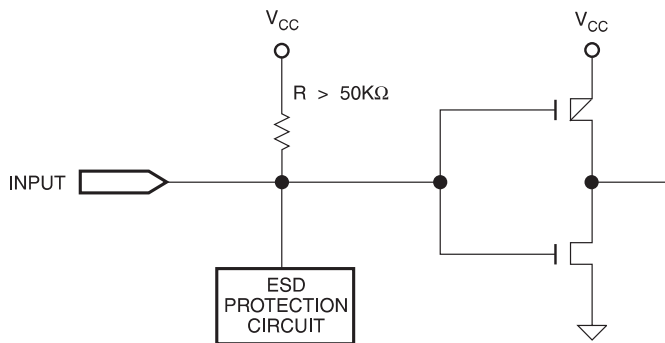
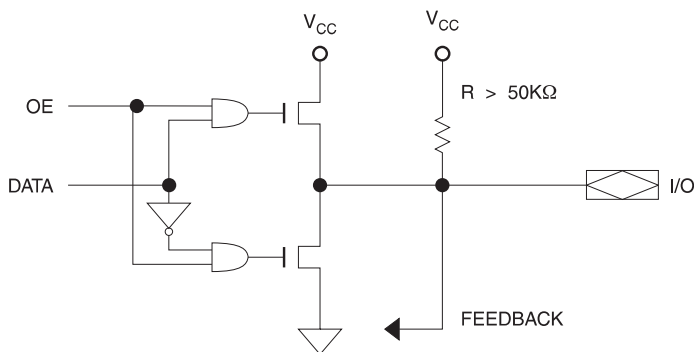
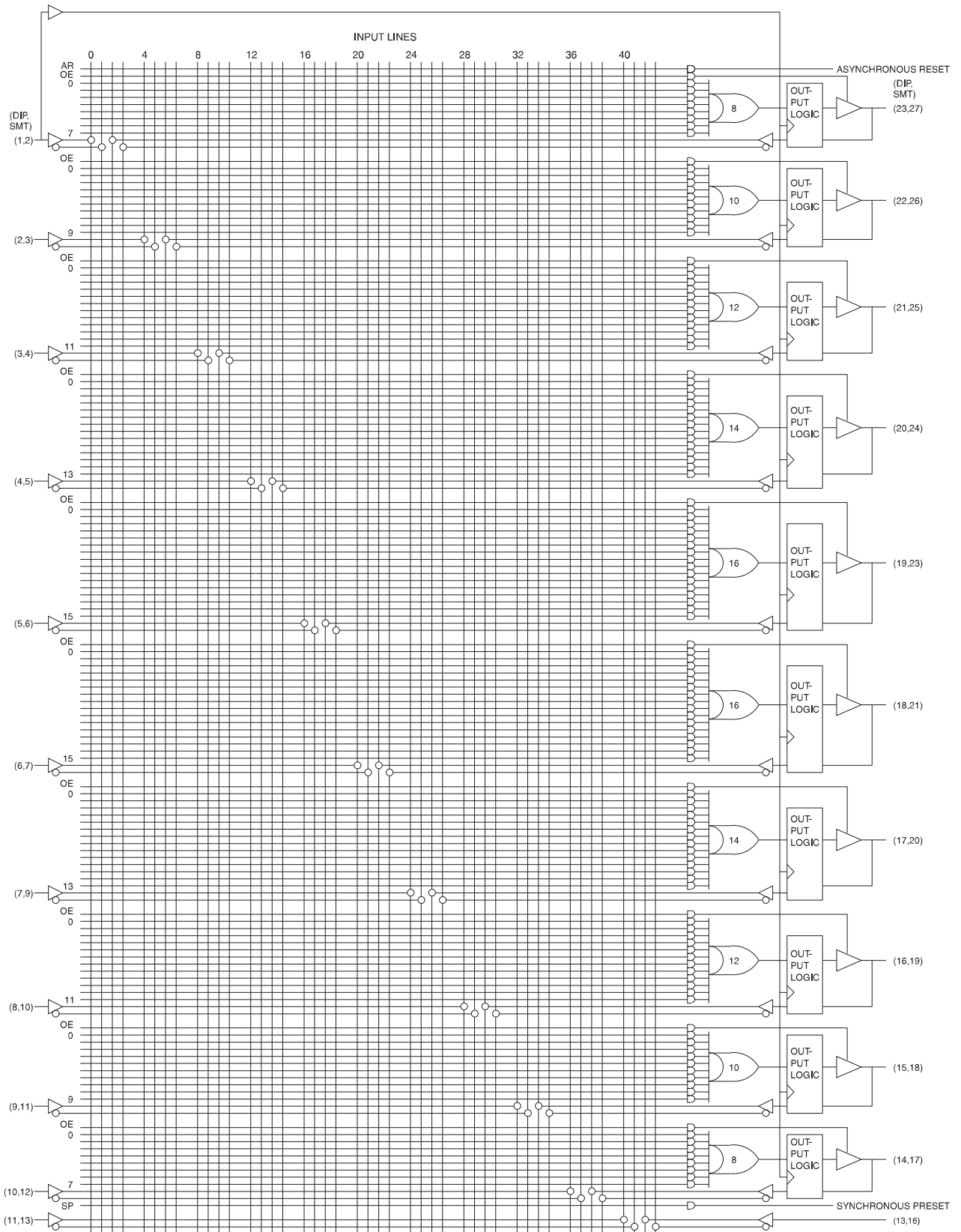


Figure 14-2. I/O Diagram

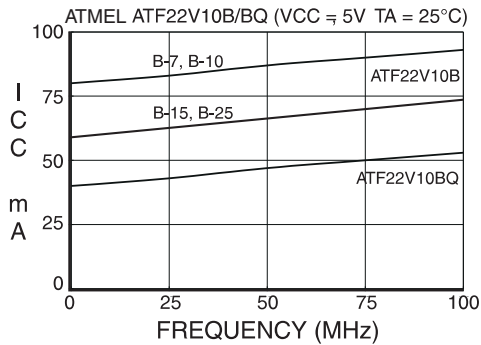


**Figure 14-3. Functional Logic Diagram Atmel ATF22V10B**

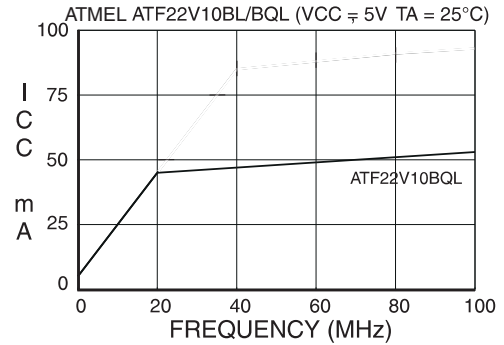




SUPPLY CURRENT vs. INPUT FREQUENCY



SUPPLY CURRENT vs. INPUT FREQUENCY



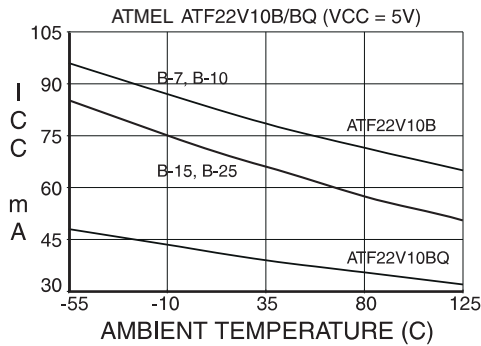
SUPPLY CURRENT vs. SUPPLY VOLTAGE



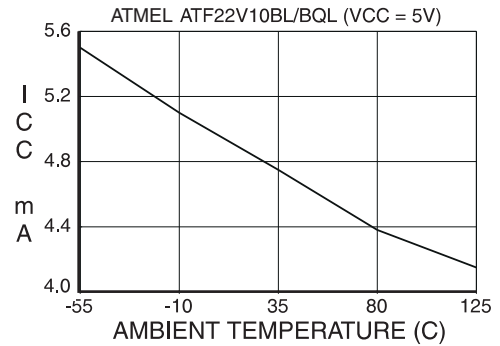
SUPPLY CURRENT vs. SUPPLY VOLTAGE



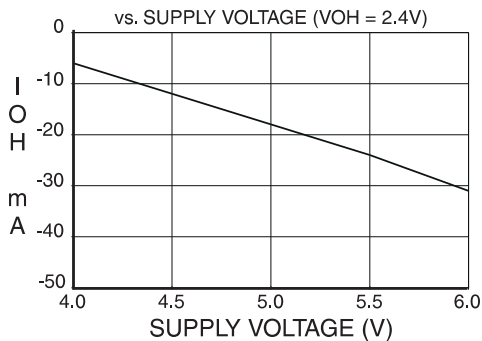
SUPPLY CURRENT vs. AMBIENT TEMPERATURE



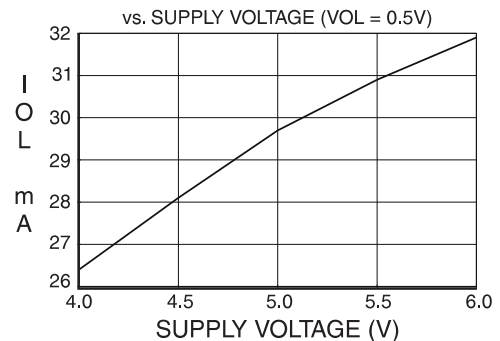
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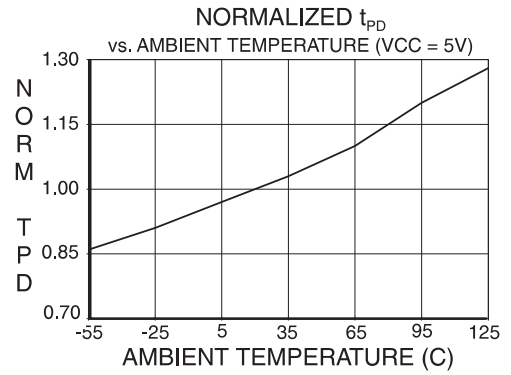
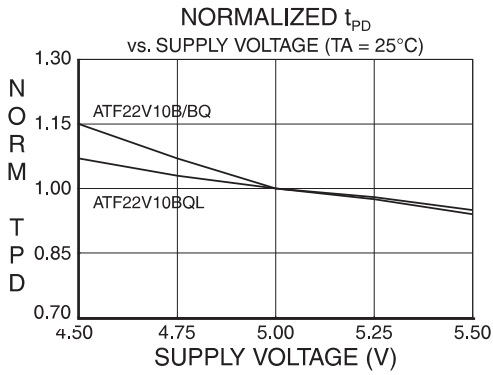
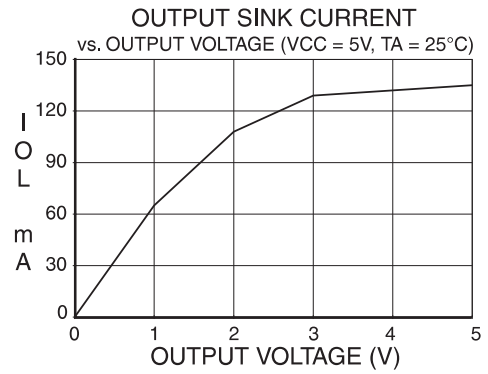
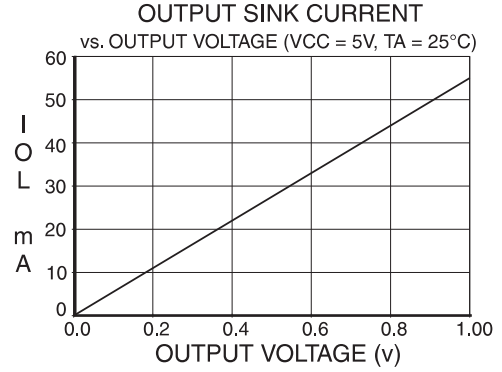
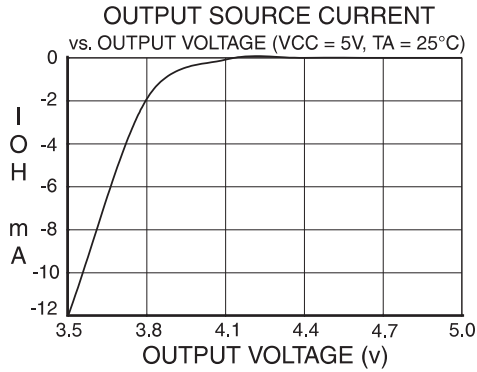


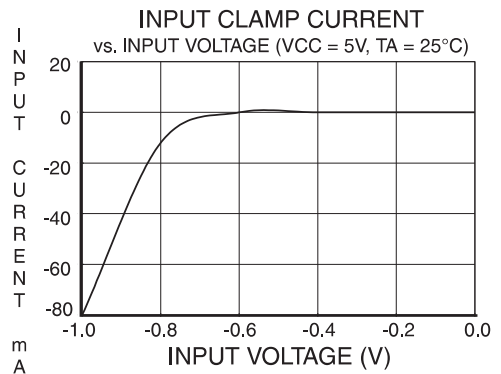
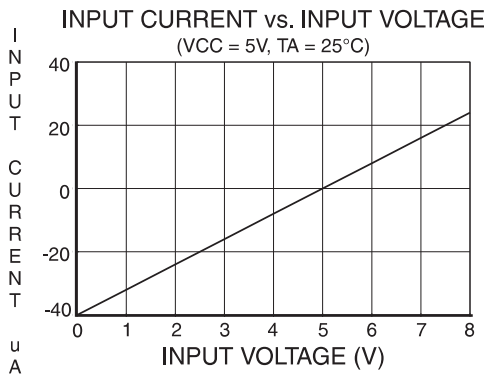
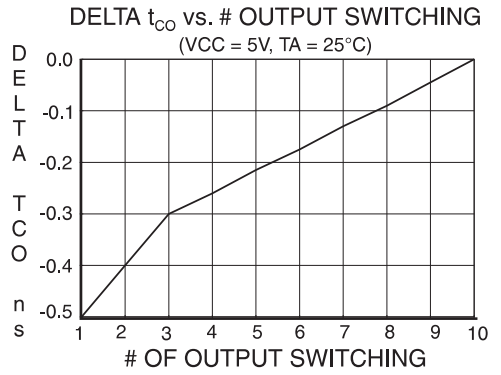
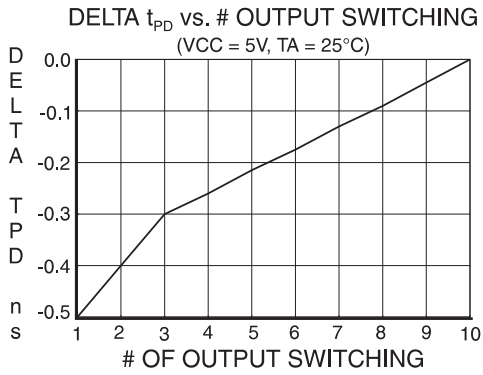
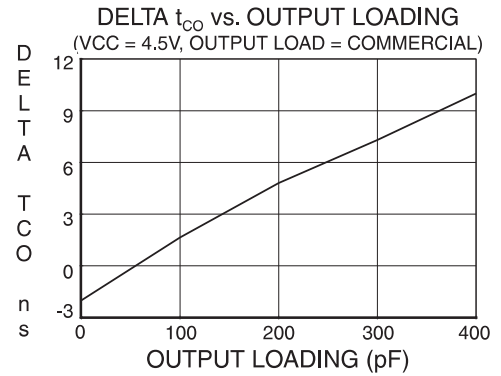
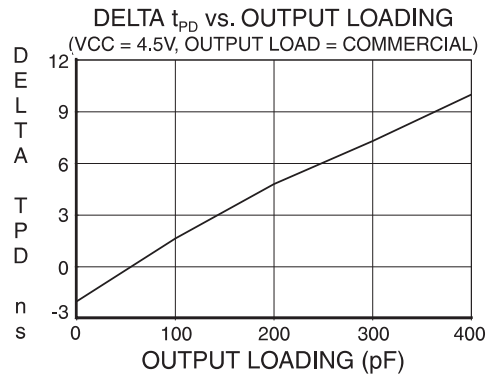
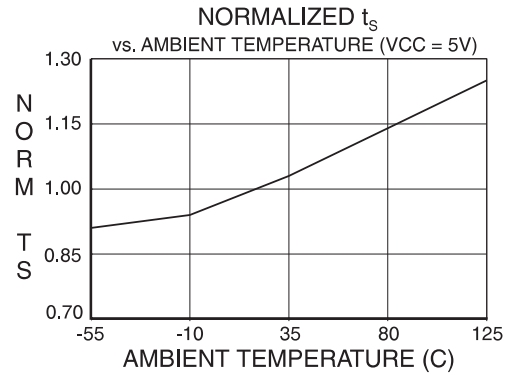
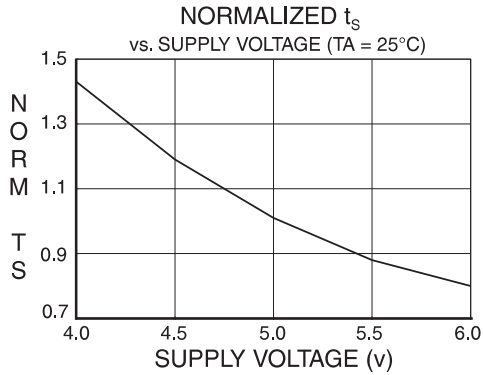
OUTPUT SOURCE CURRENT



OUTPUT SINK CURRENT







## 15. Ordering Information

### 15.1 Atmel ATF22V10B<sup>(2)</sup> Ordering Detail

$t_{PD}$ (ns)	$t_S$ (ns)	$t_{CO}$ (ns)	Ordering Code	Package	Operation Range
10	4.5	6.5	ATF22V10B-10GM/883 ATF22V10B-10NM/883	24D3 28L	Military/883C (-55°C to 125°C) Class B, Fully Compliant
			5962-89841 06LA 5962-89841 063X	24D3 28L	Military (-55°C to 125°C) Class B, Fully Compliant
15	10	8	ATF22V10B-15GM/883 ATF22V10B-15NM/883	24D3 28L	Military/883C (-55°C to 125°C) Class B, Fully Compliant
			5962-89841 03LA 5962-89841 033X	24D3 28L	Military (-55°C to 125°C) Class B, Fully Compliant

### 15.2 Atmel ATF22V10BQ(L)<sup>(1,2)</sup> Ordering Detail

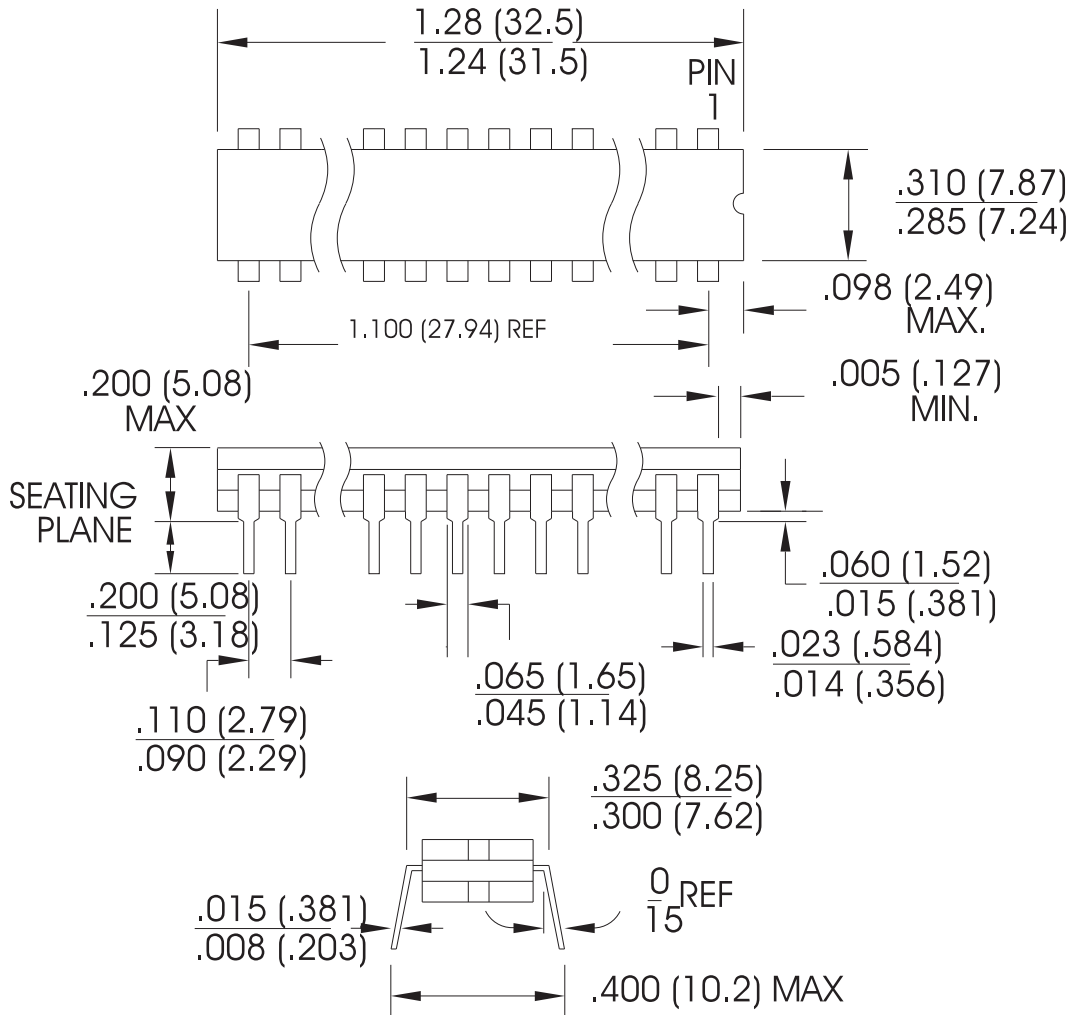
$t_{PD}$ (ns)	$t_S$ (ns)	$t_{CO}$ (ns)	Ordering Code	Package	Operation Range
20	14	12	ATF22V10BQL-20GM/883 ATF22V10BQL-20NM/883	24D3 28L	Military/883C (-55°C to 125°C) Class B, Fully Compliant
			5962-89841 14 LA 5962-89841 14 3X	24D3 28L	Military (-55°C to 125°C) Class B, Fully Compliant
25	15	15	ATF22V10BQL-25GM/883 ATF22V10BQL-25NM/883	24D3 28L	Military/883C (-55°C to 125°C) Class B, Fully Compliant
			5962-89841 13 LA 5962-89841 13 3X	24D3 28L	Military (-55°C to 125°C) Class B, Fully Compliant

- Notes: 1. The shaded devices are obsolete  
2. Please see DSCC DWG for military parts

16. Packaging Information

24D3

24D3, 24-lead, 0.300" Wide. Non-windowed,  
 Ceramic Dual Inline Package (Cerdip)  
 Dimensions in Millimeters and (Inches)\*  
 MIL-STD-1835 D-9 CONFIG A (Glass Sealed)



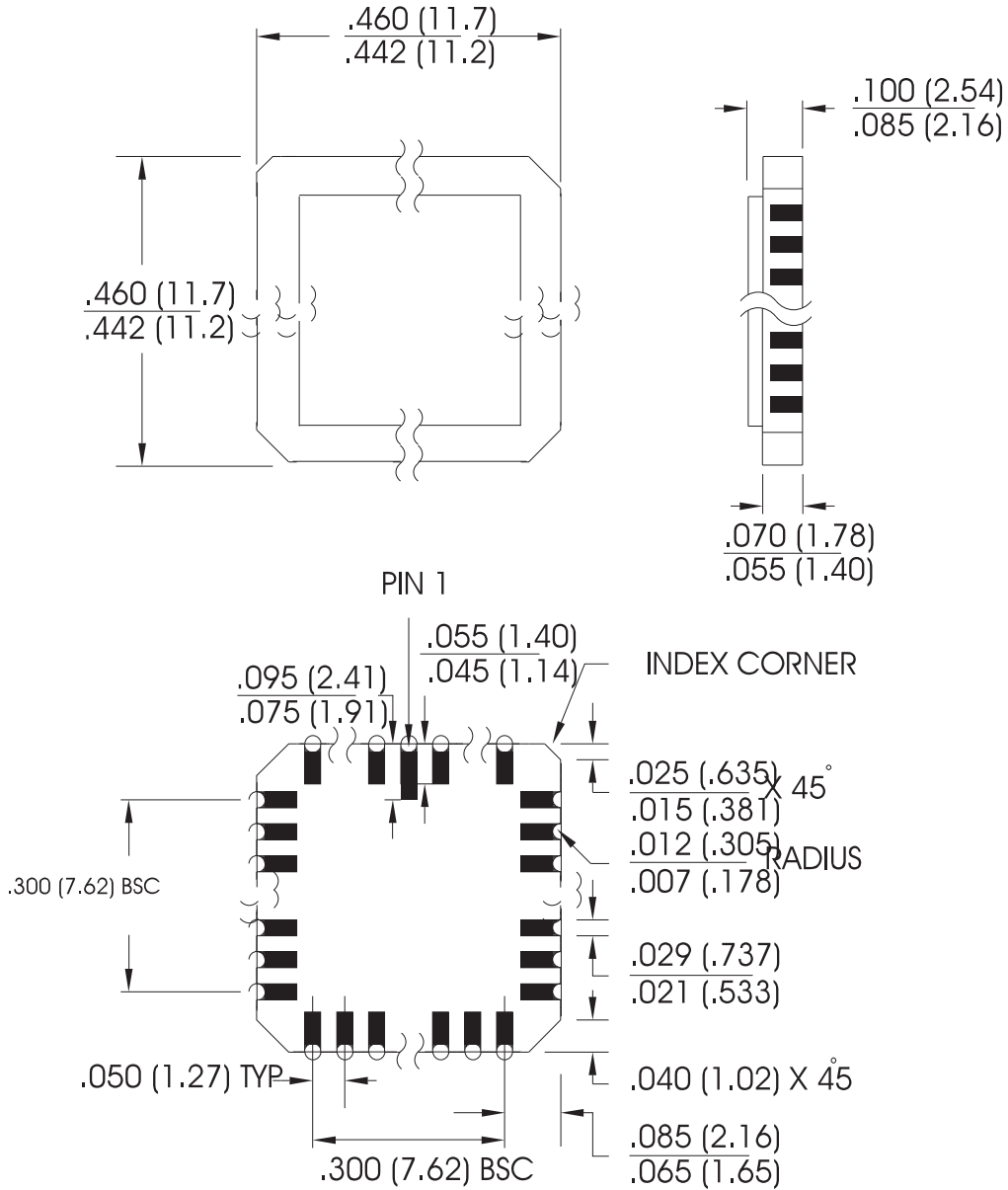
\*Controlling dimension: Inches

REV. A 04/11/2001

## 28L

28L, 28-pad, Non-windowed, Ceramic lid, Leadless Chip Carrier (LCC)

Dimensions in Millimeters and (Inches)\*  
MIL-STD-1835 C-4



\*Controlling dimension: Inches

## 17. Revision History

Doc. Rev.	Date	Comments
0250M	07/2010	Removed all commercial and industrial grade leaded part offerings